

Quad 2-input NAND Schmitt Trigger

CJ74HC/HCT132 Logic

1 Introduction

The CJ74HC/HCT132 is a quad 2-input NAND gate with Schmitt-trigger inputs.

2 Available Packages

PART NUMBER	PACKAGE
CJ74HC132	SOP14
	TSSOP14
CJ74HCT132	SOP14
	TSSOP14

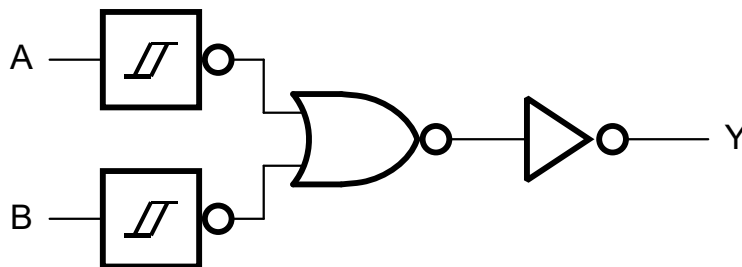
Note: For all available packages, please refer to the part Orderable Information.

3 Features

- Input levels:
 - For CJ74HC132: CMOS level
 - For CJ74HCT132: TTL level
- Low-power dissipation
- Specified from -40°C to +125°C

4 Applications

- Alarm / tamper detect circuit
- S-R latch



Logic diagram

5 Orderable Information

DEVICE	PACKAGE	OP TEMP	ECO PLAN	MSL	PACKING OPTION	SORT
CJ74HC132ADN	SOP14	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 4000 Units / Reel	Active
CJ74HCT132ADN	SOP14	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 4000 Units / Reel	Active
CJ74HC132BDN	TSSOP14	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 5000 Units / Reel	Active
CJ74HCT132BDN	TSSOP14	-40~125°C	RoHS & Green	Level 3 168HR	Tape and Reel 5000 Units / Reel	Active

Note:

ECO PLAN: For the RoHS and Green certification standards of this product, please refer to the official report provided by JSCJ.

MSL: Moisture Sensitivity Level. Determined according to JEDEC industry standard classification.

SORT: Specifically defined as follows:

Active: Recommended for new products;

Customized: Products manufactured to meet the specific needs of customers;

Preview: The device has been released and has not been fully mass produced. The sample may or may not be available;

NoRD: It is not recommended to use the device for new design. The device is only produced for the needs of existing customers;

Obsolete: The device has been discontinued.

6 Pin Configuration and Marking Information

6.1 Pin Configuration

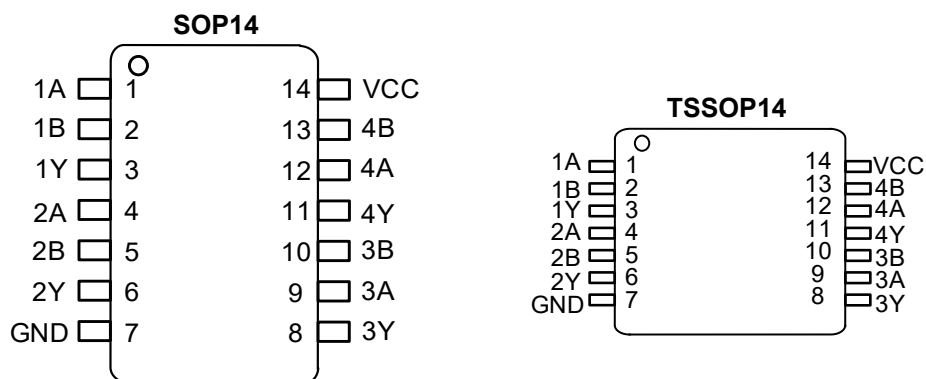


Figure 6-1 Pin configuration

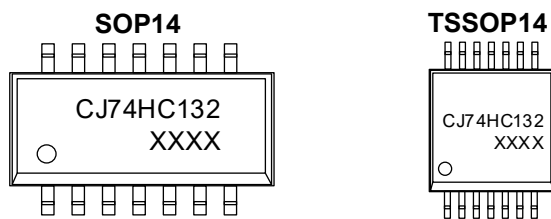
6.2 Pin Function

PIN		I/O ⁽¹⁾	DESCRIPTION
No.	NAME		
1	1A	I	Data input
2	1B	I	Data input
3	1Y	O	Data output
4	2A	I	Data input
5	2B	I	Data input
6	2Y	O	Data output
7	GND	G	Ground (0V)
8	3Y	O	Data output
9	3A	I	Data input
10	3B	I	Data input
11	4Y	O	Data output
12	4A	I	Data input
13	4B	I	Data input
14	VCC	P	Supply voltage

(1) I-Input, O-Output, P-Power, G-Ground

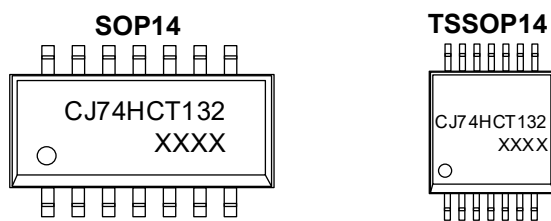
6.3 Marking Information

6.3.1 CJ74HC132



XXXX: Code, indicates weekly record information.

6.3.2 CJ74HCT132



XXXX: Code, indicates weekly record information.

7 Specifications

7.1 Absolute Maximum Ratings

Voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	MAX.	UNIT
V _{CC}	Supply voltage	-		-0.5	+7	V
I _{IK}	Input clamping current	V _I < -0.5V or V _I > V _{CC} +0.5V		-	±20	mA
I _{OK}	Output clamping current	V _O < -0.5V or V _O > V _{CC} +0.5V		-	±20	mA
I _O	Output current	-0.5V < V _O < V _{CC} +0.5V		-	±25	mA
I _{CC}	Supply current	-		-	50	mA
I _{GND}	Ground current	-		-50	-	mA
P _{tot}	Total power dissipation	-		-	500	mW
T _{stg}	Storage temperature	-		-65	+150	°C
T _L	Soldering temperature	10s	SOP/TSSOP	-	260	°C

Note: Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to GND. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

7.2 Recommended Operating Conditions

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC132						
V _{CC}	Supply voltage	-	2.0	5.0	6.0	V
V _I	Input voltage	-	0	-	V _{CC}	V
V _O	Output voltage	-	0	-	V _{CC}	V
T _{amb}	Ambient temperature	-	-40	-	+125	°C
CJ74HCT132						
V _{CC}	Supply voltage	-	4.5	5.0	5.5	V
V _I	Input voltage	-	0	-	V _{CC}	V
V _O	Output voltage	-	0	-	V _{CC}	V
T _{amb}	Ambient temperature	-	-40	-	+125	°C

7.3 ESD Ratings

SYMBOL	ESD RATINGS		VALUE	UNIT
V _{ESD-HBM}	Electrostatic discharge	Human body model (HBM) ⁽¹⁾	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.4 Electrical Characteristics

7.4.1 DC Characteristics 1

$T_{amb}=25^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
CJ74HC132							
V _{OH}	HIGH-level output voltage	V _I =V _{T+} or V _{T-}	I _O =-20uA; V _{CC} =2.0V	1.9	2.0	-	V
			I _O =-20uA; V _{CC} =4.5V	4.4	4.5	-	V
			I _O =-20uA; V _{CC} =6.0V	5.9	6.0	-	V
			I _O =-4.0mA; V _{CC} =4.5V	3.98	4.32	-	V
			I _O =-5.2mA; V _{CC} =6.0V	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	V _I =V _{T+} or V _{T-}	I _O =20uA; V _{CC} =2.0V	-	0	0.1	V
			I _O =20uA; V _{CC} =4.5V	-	0	0.1	V
			I _O =20uA; V _{CC} =6.0V	-	0	0.1	V
			I _O =4.0mA; V _{CC} =4.5V	-	0.15	0.26	V
			I _O =5.2mA; V _{CC} =6.0V	-	0.16	0.26	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =6.0V		-	-	±1	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; I _O =0A; V _{CC} =6.0V		-	-	2.0	uA
C _I	Input capacitance	-		-	3.5	-	pF
CJ74HCT132							
V _{OH}	HIGH-level output voltage	V _I =V _{T+} or V _{T-}	I _O =-20uA; V _{CC} =4.5V	4.4	4.5	-	V
			I _O =-4.0mA; V _{CC} =4.5V	3.98	4.32	-	V
V _{OL}	LOW-level output voltage	V _I =V _{T+} or V _{T-}	I _O =20uA; V _{CC} =4.5V	-	0	0.1	V
			I _O =4.0mA; V _{CC} =4.5V	-	0.15	0.26	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =5.5V		-	-	±1	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; I _O =0A; V _{CC} =5.5V		-	-	2.0	uA
ΔI _{CC}	Additional supply current	Per input pin; V _I =V _{CC} -2.1V; I _O =0A; Other inputs at V _{CC} or GND; V _{CC} =4.5V to 5.5V		-	-	108	uA
C _I	Input capacitance	-		-	3.5	-	pF

7.4.2 DC Characteristics 2

$T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
CJ74HC132							
V _{OH}	HIGH-level output voltage	V _I =V _{T+} or V _{T-}	I _O =-20uA; V _{CC} =2.0V	1.9	-	-	V
			I _O =-20uA; V _{CC} =4.5V	4.4	-	-	V
			I _O =-20uA; V _{CC} =6.0V	5.9	-	-	V
			I _O =-4.0mA; V _{CC} =4.5V	3.84	-	-	V
			I _O =-5.2mA; V _{CC} =6.0V	5.34	-	-	V
V _{OL}	LOW-level output voltage	V _I =V _{T+} or V _{T-}	I _O =20uA; V _{CC} =2.0V	-	-	0.1	V
			I _O =20uA; V _{CC} =4.5V	-	-	0.1	V
			I _O =20uA; V _{CC} =6.0V	-	-	0.1	V
			I _O =4.0mA; V _{CC} =4.5V	-	-	0.33	V
			I _O =5.2mA; V _{CC} =6.0V	-	-	0.33	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =6.0V		-	-	±1	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; I _O =0A; V _{CC} =6.0V		-	-	20	uA
CJ74HCT132							
V _{OH}	HIGH-level output voltage	V _I =V _{T+} or V _{T-}	I _O =-20uA; V _{CC} =4.5V	4.4	-	-	V
			I _O =-4.0mA; V _{CC} =4.5V	3.84	-	-	V
V _{OL}	LOW-level output voltage	V _I =V _{T+} or V _{T-}	I _O =20uA; V _{CC} =4.5V	-	-	0.1	V
			I _O =4.0mA; V _{CC} =4.5V	-	-	0.33	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =5.5V		-	-	±1	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; I _O =0A; V _{CC} =5.5V		-	-	20	uA
ΔI _{CC}	Additional supply current	Per input pin; V _I =V _{CC} -2.1V; I _O =0A; Other inputs at V _{CC} or GND; V _{CC} =4.5V to 5.5V		-	-	135	uA

7.4.3 DC Characteristics 3

$T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
CJ74HC132							
V _{OH}	HIGH-level output voltage	V _I =V _{T+} or V _{T-}	I _O =-20uA; V _{CC} =2.0V	1.9	-	-	V
			I _O =-20uA; V _{CC} =4.5V	4.4	-	-	V
			I _O =-20uA; V _{CC} =6.0V	5.9	-	-	V
			I _O =-4.0mA; V _{CC} =4.5V	3.7	-	-	V
			I _O =-5.2mA; V _{CC} =6.0V	5.2	-	-	V
V _{OL}	LOW-level output voltage	V _I =V _{T+} or V _{T-}	I _O =20uA; V _{CC} =2.0V	-	-	0.1	V
			I _O =20uA; V _{CC} =4.5V	-	-	0.1	V
			I _O =20uA; V _{CC} =6.0V	-	-	0.1	V
			I _O =4.0mA; V _{CC} =4.5V	-	-	0.4	V
			I _O =5.2mA; V _{CC} =6.0V	-	-	0.4	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =6.0V		-	-	±1	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; I _O =0A; V _{CC} =6.0V		-	-	40	uA
CJ74HCT132							
V _{OH}	HIGH-level output voltage	V _I =V _{T+} or V _{T-}	I _O =-20uA; V _{CC} =4.5V	4.4	-	-	V
			I _O =-4.0mA; V _{CC} =4.5V	3.7	-	-	V
V _{OL}	LOW-level output voltage	V _I =V _{T+} or V _{T-}	I _O =20uA; V _{CC} =4.5V	-	-	0.1	V
			I _O =4.0mA; V _{CC} =4.5V	-	-	0.4	V
I _I	Input leakage current	V _I =V _{CC} or GND; V _{CC} =5.5V		-	-	±1	uA
I _{CC}	Supply current	V _I =V _{CC} or GND; I _O =0A; V _{CC} =5.5V		-	-	40	uA
ΔI _{CC}	Additional supply current	Per input pin; V _I =V _{CC} -2.1V; I _O =0A; Other inputs at V _{CC} or GND; V _{CC} =4.5V to 5.5V		-	-	147	uA

7.4.4 AC Characteristics 1

T_{amb}=25°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC132						
t _{pd}	nA, nB to nY propagation delay	See Figure 8-5 ⁽¹⁾	V _{CC} =2.0V	-	36	125 ns
			V _{CC} =4.5V	-	13	25 ns
			V _{CC} =5.0V; C _L =15pF	-	11	- ns
			V _{CC} =6.0V	-	10	21 ns
t _t	Transition time	See Figure 8-5 ⁽²⁾	V _{CC} =2.0V	-	19	75 ns
			V _{CC} =4.5V	-	7	15 ns
			V _{CC} =6.0V	-	6	13 ns
C _{PD}	Power dissipation capacitance	Per package; V _I = GND to V _{CC} ⁽³⁾	-	24	-	pF
CJ74HCT132						
t _{pd}	nA, nB to nY propagation delay	See Figure 8-5 ⁽¹⁾	V _{CC} =4.5V	-	20	33 ns
			V _{CC} =5.0V; C _L =15pF	-	17	- ns
t _t	Transition time	See Figure 8-5 ⁽²⁾	V _{CC} =4.5V	-	7	15 ns
C _{PD}	Power dissipation capacitance	Per package; V _I = GND to V _{CC} -1.5V ⁽³⁾	-	20	-	pF

(1) t_{pd} is the same as t_{PLH} and t_{PHL}.

(2) t_t is the same as t_{THL} and t_{TLH}.

(3) C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$P_D = (C_{PD} \times V_{CC}^2 \times f_i \times N) + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

f_i=input frequency in MHz;

f_o=output frequency in MHz;

C_L=output load capacitance in pF;

V_{CC}=supply voltage in V;

N=number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$ =sum of outputs.

7.4.5 AC Characteristics 2

T_{amb}=−40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
CJ74HC132							
t _{pd}	nA, nB to nY propagation delay	See Figure 8-5 ⁽¹⁾	V _{CC} =2.0V	-	-	155	ns
			V _{CC} =4.5V	-	-	31	ns
			V _{CC} =6.0V	-	-	26	ns
t _t	Transition time	See Figure 8-5 ⁽²⁾	V _{CC} =2.0V	-	-	95	ns
			V _{CC} =4.5V	-	-	19	ns
			V _{CC} =6.0V	-	-	16	ns
CJ74HCT132							
t _{pd}	nA, nB to nY propagation delay	See Figure 8-5 ⁽¹⁾	V _{CC} =4.5V	-	-	41	ns
t _t	Transition time	See Figure 8-5 ⁽²⁾	V _{CC} =4.5V	-	-	19	ns

(1) t_{pd} is the same as t_{PLH} and t_{PHL}.

(2) t_t is the same as t_{THL} and t_{TLH}.

7.4.6 AC Characteristics 3

T_{amb}=−40°C to +125°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
CJ74HC132							
t _{pd}	nA, nB to nY propagation delay	See Figure 8-5 ⁽¹⁾	V _{CC} =2.0V	-	-	190	ns
			V _{CC} =4.5V	-	-	38	ns
			V _{CC} =6.0V	-	-	32	ns
t _t	Transition time	See Figure 8-5 ⁽²⁾	V _{CC} =2.0V	-	-	110	ns
			V _{CC} =4.5V	-	-	22	ns
			V _{CC} =6.0V	-	-	19	ns
CJ74HCT132							
t _{pd}	nA, nB to nY propagation delay	See Figure 8-5 ⁽¹⁾	V _{CC} =4.5V	-	-	50	ns
t _t	Transition time	See Figure 8-5 ⁽²⁾	V _{CC} =4.5V	-	-	22	ns

(1) t_{pd} is the same as t_{PLH} and t_{PHL}.

(2) t_t is the same as t_{THL} and t_{TLH}.

7.4.7 Transfer characteristics 1

T_{amb}=25°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC132						
V _{T+}	Positive-going threshold voltage	V _{CC} =2.0V	0.7	1.18	1.5	V
		V _{CC} =4.5V	1.7	2.38	3.15	V
		V _{CC} =6.0V	2.1	3.14	4.2	V
V _{T-}	Negative-going threshold voltage	V _{CC} =2.0V	0.3	0.63	1.0	V
		V _{CC} =4.5V	0.9	1.67	2.2	V
		V _{CC} =6.0V	1.2	2.26	3.0	V
V _H	Hysteresis voltage	V _{CC} =2.0V	0.2	0.55	1.0	V
		V _{CC} =4.5V	0.4	0.71	1.4	V
		V _{CC} =6.0V	0.6	0.88	1.6	V
CJ74HCT132						
V _{T+}	Positive-going threshold voltage	V _{CC} =4.5V	1.2	1.41	1.9	V
		V _{CC} =5.5V	1.4	1.59	2.1	V
V _{T-}	Negative-going threshold voltage	V _{CC} =4.5V	0.5	0.85	1.2	V
		V _{CC} =5.5V	0.6	0.99	1.4	V
V _H	Hysteresis voltage	V _{CC} =4.5V	0.4	0.56	-	V
		V _{CC} =5.5V	0.4	0.6	-	V

7.4.8 Transfer characteristics 2

T_{amb}=-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC132						
V _{T+}	Positive-going threshold voltage	V _{CC} =2.0V	0.7	-	1.5	V
		V _{CC} =4.5V	1.7	-	3.15	V
		V _{CC} =6.0V	2.1	-	4.2	V
V _{T-}	Negative-going threshold voltage	V _{CC} =2.0V	0.3	-	1.0	V
		V _{CC} =4.5V	0.9	-	2.2	V
		V _{CC} =6.0V	1.2	-	3.0	V
V _H	Hysteresis voltage	V _{CC} =2.0V	0.2	-	1.0	V
		V _{CC} =4.5V	0.4	-	1.4	V
		V _{CC} =6.0V	0.6	-	1.6	V
CJ74HCT132						
V _{T+}	Positive-going threshold voltage	V _{CC} =4.5V	1.2	-	1.9	V
		V _{CC} =5.5V	1.4	-	2.1	V
V _{T-}	Negative-going	V _{CC} =4.5V	0.5	-	1.2	V

	threshold voltage	$V_{CC}=5.5V$	0.6	-	1.4	V
V_H	Hysteresis voltage	$V_{CC}=4.5V$	0.4	-	-	V
		$V_{CC}=5.5V$	0.4	-	-	V

7.4.9 Transfer characteristics 3

$T_{amb}=-40^{\circ}C$ to $+125^{\circ}C$, voltages are referenced to GND (ground=0V), unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
CJ74HC132						
V _{T+}	Positive-going threshold voltage	V _{CC} =2.0V	0.7	-	1.5	V
		V _{CC} =4.5V	1.7	-	3.15	V
		V _{CC} =6.0V	2.1	-	4.2	V
V _{T-}	Negative-going threshold voltage	V _{CC} =2.0V	0.3	-	1.0	V
		V _{CC} =4.5V	0.9	-	2.2	V
		V _{CC} =6.0V	1.2	-	3.0	V
V _H	Hysteresis voltage	V _{CC} =2.0V	0.2	-	1.0	V
		V _{CC} =4.5V	0.4	-	1.4	V
		V _{CC} =6.0V	0.6	-	1.6	V
CJ74HCT132						
V _{T+}	Positive-going threshold voltage	V _{CC} =4.5V	1.2	-	1.9	V
		V _{CC} =5.5V	1.4	-	2.1	V
V _{T-}	Negative-going threshold voltage	V _{CC} =4.5V	0.5	-	1.2	V
		V _{CC} =5.5V	0.6	-	1.4	V
V _H	Hysteresis voltage	V _{CC} =4.5V	0.4	-	-	V
		V _{CC} =5.5V	0.4	-	-	V

8 Detailed Description

8.1 Overview

The CJ74HC/HCT132 is a quad 2-input NAND gate with Schmitt-trigger inputs.

8.2 Functional Block Diagram

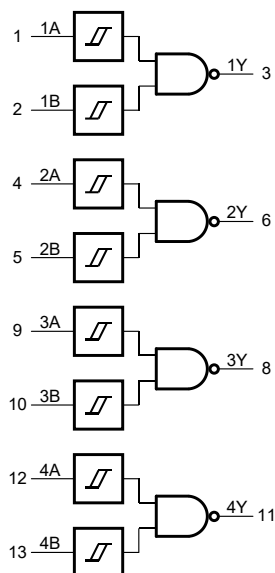


Figure 8-1 Logic symbol

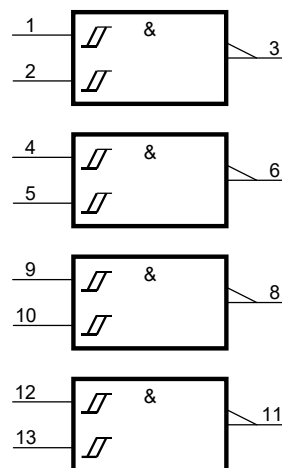


Figure 8-2 IEC logic symbol

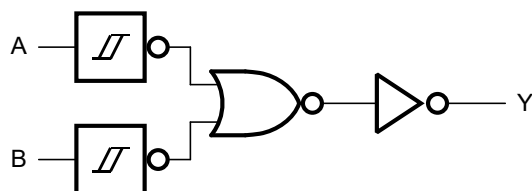


Figure 8-3 Logic diagram for one gate

8.3 Function Table⁽¹⁾

INPUT		OUTPUT
nA	nB	nY
L	L	H
L	H	H
H	L	H
H	H	L

(1) H=HIGH voltage level; L=LOW voltage level; X=don't care.

8.4 Testing Circuit

8.4.1 AC Testing Circuit

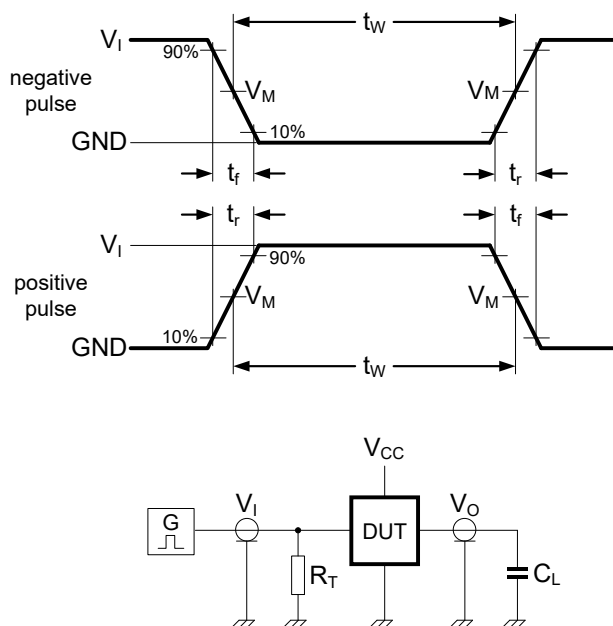


Figure 8-4 Test circuit for measuring switching times

Definitions for test circuit:

C_L =load capacitance including jig and probe capacitance.

R_T =termination resistance should be equal to the output impedance Z_o of the pulse generator.

8.4.2 AC Testing Waveforms

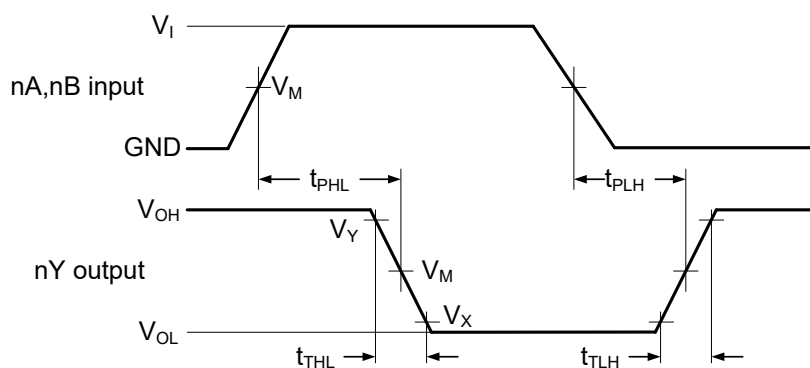


Figure 8-5 Input to output propagation delays

8.4.3 Transfer Characteristics Waveforms

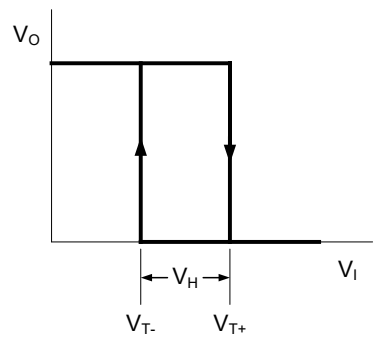


Figure 8-6 Transfer characteristics

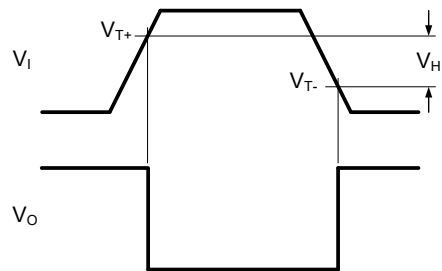


Figure 8-7 Transfer characteristics definitions

8.4.4 Measurement Points

TYPE	INPUT	OUTPUT		
	V _M	V _M	V _X	V _Y
CJ74HC132	0.5xV _{CC}	0.5xV _{CC}	0.1xV _{CC}	0.9xV _{CC}
CJ74HCT132	1.3V	1.3V	0.1xV _{CC}	0.9xV _{CC}

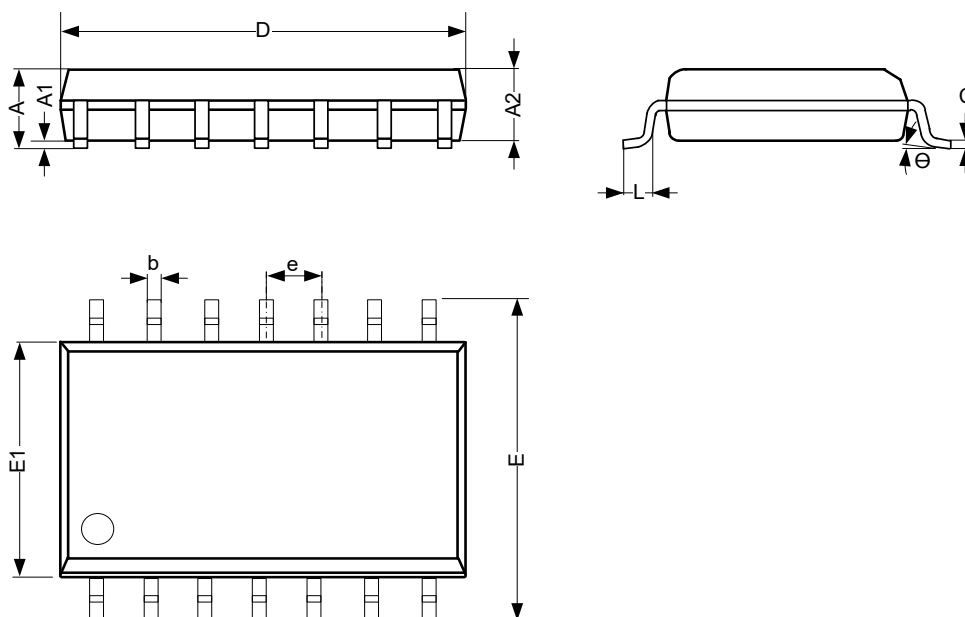
8.4.5 Test Data

TYPE	INPUT		LOAD	TEST
	V _I	t _r ,t _f	C _L	
CJ74HC132	V _{CC}	6.0ns	15pF,50pF	t _{PLH} ,t _{PHL}
CJ74HCT132	3.0V	6.0ns	15pF,50pF	t _{PLH} ,t _{PHL}

9 Mechanical Information

9.1 SOP14 Mechanical Information

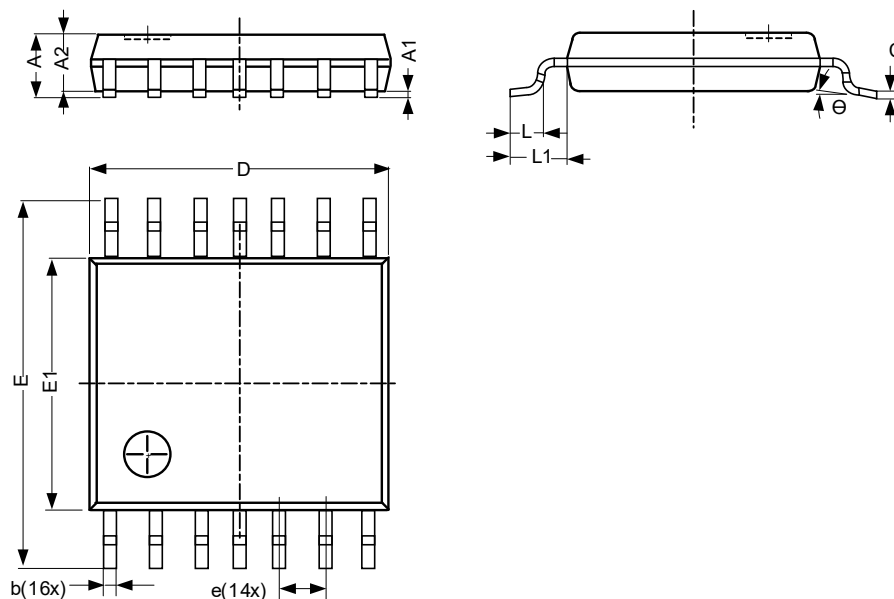
9.1.1 SOP14 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	1.50	-	1.75
A1	0.05	-	0.25
A2	1.30	-	-
b	0.33	-	0.50
c	0.19	-	0.25
D	8.43	-	8.76
E	5.80	-	6.25
E1	3.75	-	4.00
e	1.27 BSC		
L	0.40	-	0.89
θ	0°	-	8°
Unit: mm			

9.2 TSSOP14 Mechanical Information

9.2.1 TSSOP14 Outline Dimensions



SYMBOL	Dimensions In Millimeters		
	Min.	Typ.	Max.
A	-	-	1.20
A1	0.05	-	0.15
A2	0.80	-	1.05
b	0.19	-	0.30
c	0.09	-	0.20
D	4.90	-	5.10
E	6.20	-	6.60
E1	4.30	-	4.50
e	0.65 BSC		
L	0.45	-	0.75
L1	-	1.00	-
θ	0°	-	8°
Unit: mm			

10 Notes and Revision History

10.1 Associated Product Family and Others

To view other products of the same type or IC products of other types, click the official website of JSCJ -- <https://www.jscj-elec.com> for more details.

10.2 Notes

Electrostatic Discharge Caution



This IC may be damaged by ESD. Relevant personnel shall comply with correct installation and use specifications to avoid ESD damage to the IC. If appropriate measures are not taken to prevent ESD damage, the hazards caused by ESD include but are not limited to degradation of integrated circuit performance or complete damage of integrated circuit. For some precision integrated circuits, a very small parameter change may cause the whole device to be inconsistent with its published specifications.

DISCLAIMER

IMPORTANT NOTICE, PLEASE READ CAREFULLY

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